



Docket No.: 57810-031

**PATENT**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of	:	Customer Number: 20277
Tatsuya KUNISATO, et al.	:	Confirmation Number: 4343
Serial No.: 10/081,842	:	Group Art Unit: 2815
Filed: February 25, 2002	:	Examiner: C. Lam
For: NITRIDE-BASED SEMICONDUCTOR ELEMENT AND METHOD OF FORMING NITRIDE-BASED SEMICONDUCTOR	:	

RECEIVED  
DEC 15 2003  
TC 1700

**AMENDMENT**

Mail Stop Non-Fee Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

The following Amendment and Remarks are submitted in response to the Office

Action dated July 1, 2003.

RECEIVED  
DEC - 8 2003  
TECHNOLOGY CENTER 28000